ML7XX4 SERIES

InGaAsP—MQW—DFB LASER DIODES

TYPE NAME ML7924

DESCRIPTION

ML7XX4 series are MQW*—DFB** laser diodes emitting light beam around 1310nm.

They are well suited for light source in longdistance analog transmission system for example cable television (CATV).The ML7924 are specially designed for fiber modules and mount on flat open packages.

Rear output can be used for automatic power control of the laser.

* MQW : Multiple Quantum Well

** DFB : Distributed Feedback

FEATURES

- Excellent low distortion characteristic
  CSO typical-60dBc/CTB typical-65dBc
  under NTSC 78-channel transmission test
  - Modulation depth m = 3.5%/channel
  - Po = 10mW to 25mW
  - 20km single mode fiber
- Low relative intensity noise characteristic
  (typical - 155dB/Hz)
- Low threshold current (typical 10mA)
- High-side mode suppression ratio (typical 40dB)

APPLICATION

Long-distance analog transmission system, especially for optical CATV

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
P_O	Light output power	CW	30	mW
V_{RL}	Reverse voltage (Laser diode)	—	2	V
T_C	Case temperature	—	+20~+30	℃
T_{stg}	Storage temperature	—	−40~+100	℃

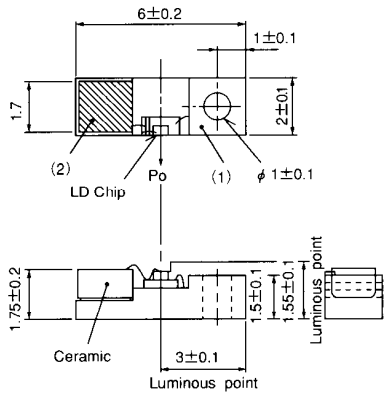
ELECTRICAL/OPTICAL CHARACTERISTICS (T_C = 25℃)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I_{th}	Threshold current	CW	—	10	20	mA
I_{OP}	Operating current	CW,Po = 10mW	—	35	60	mA
V_{OP}	Operating voltage	CW,Po = 10mW	—	1.2	1.8	V
η	Slope efficiency	CW,Po = 10mW	0.25	0.4	—	mW/mA
λ_P	Peak wavelength	CW,Po = 10mW	1290	1310	1330	nm
$\theta_{//}$	Beam divergence angle (parallel)	CW,Po = 10mW	—	25	35	deg.
$\theta_{\perp}$	Beam divergence angle (perpendicular)	CW,Po = 10mW	—	30	40	deg.
SMSR	Side mode suppression ratio	CW,Po = 10mW	30	40	—	dB
P_m	Monitoring output	CW,Po = 10mW	—	0.5	—	mW
CSO	Composite second order	78-channel transmission test, modulation depth m = 3.5%/channel, Po (average) = 10 to 25mW 20Km single mode fiber	—	−60	—	dBc
CTB	Composite triple beat		—	−65	—	dBc
CNR	Carrier to noise ratio		—	52	—	dB
RIN	Relative intensity noise	CW,Po = 10mW to 25mW,measuring frequency fm = 550MHz	—	−155	—	dB/Hz

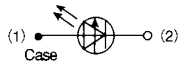
OUTLINE DRAWINGS

ML7924

Dimension : mm



(Chip carrier type)



TYPICAL CHARACTERISTICS

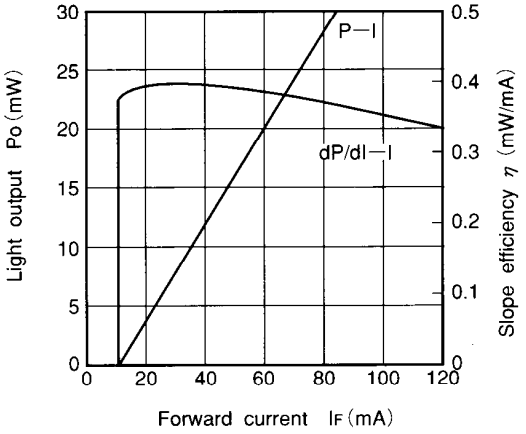


Fig.1 Light output vs. forward current

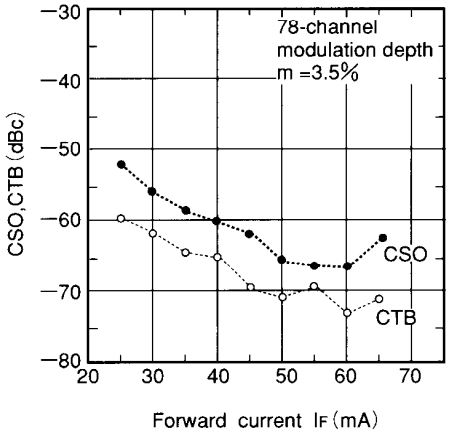


Fig.2 CSO/CTB vs. forward current

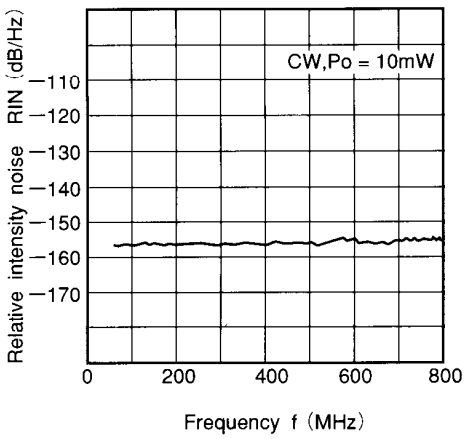


Fig.3 Relative intensity noise vs. frequency

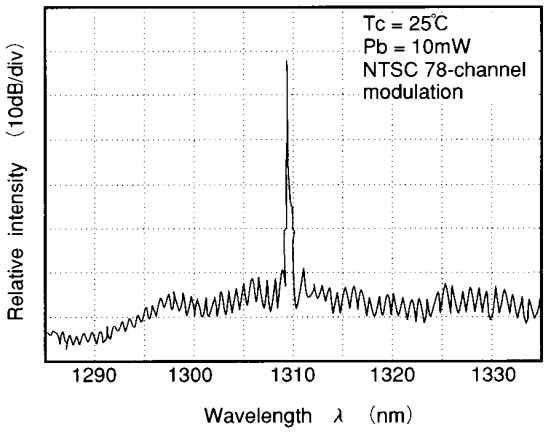


Fig.4 Spectrum under modulated operation

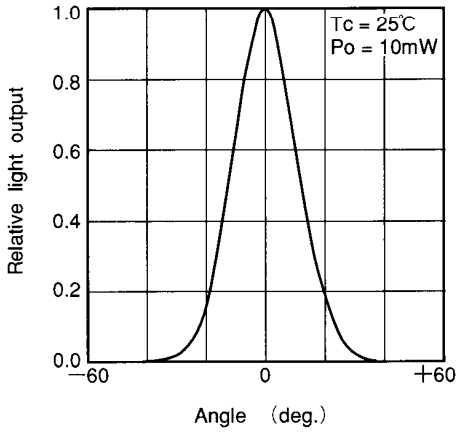


Fig.5-1 Far field pattern $\theta_{//}$

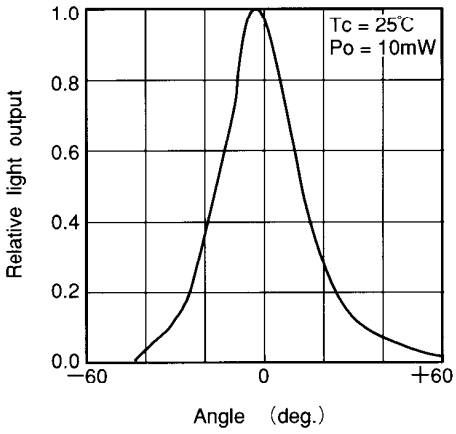


Fig.5-2 Far field pattern $\theta_{\perp}$